

20A, 100V Low V_F Trench Schottky Rectifier

FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Low power loss/ High efficiency
- High forward surge capability
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

- Case: TO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N⋅m maximum
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 1.88g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
١ _F	20	А
V _{RRM}	100	V
I _{FSM}	150	А
T _{J MAX}	150	°C
Package	TO-220AB	
Configuration	Dual d	lies









ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)			
PARAMETER	SYMBOL	TST20U100C	UNIT
Marking code on the device		TST20U100C	
Repetitive peak reverse voltage	V _{RRM}	100	V
Reverse voltage, total rms value	V _{R(RMS)}	70	V
Forward current	I _F	20	А
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	150	А
Junction temperature	TJ	-55 to +150	°C
Storage temperature	T _{STG}	-55 to +150	°C



THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-case thermal resistance	R _{eJC}	2.5	°C/W

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage per diode ⁽¹⁾	$I_F = 5A, T_J = 25^{\circ}C$	- V _F	0.56	-	V
	$I_F = 10A, T_J = 25^{\circ}C$		0.65	0.79	V
	$I_F = 5A, T_J = 125^{\circ}C$		0.49	-	V
	$I_F = 10A, T_J = 125^{\circ}C$		0.58	0.68	V
Reverse current @ rated V_R per diode ⁽²⁾	$T_J = 25^{\circ}C$	1	-	500	μA
	T _J = 125°C	I _R	-	25	mA

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE	PACKAGE	PACKING
TST20U100C	TO-220AB	50 / Tube



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$



Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics



10000 (G) 1000 100 100 (G) 1000 100 (G) 1000 (G)

Fig.2 Typical Junction Capacitance



REVERSE VOLTAGE (V)



FORWARD VOLTAGE (V)

PACKAGE OUTLINE DIMENSIONS



DIM.	Unit (mm)		Unit ((inch)
	Min.	Max.	Min.	Max.
A	4.42	4.76	0.174	0.187
A2	2.20	2.80	0.087	0.110
b	0.68	0.94	0.027	0.037
b2	1.14	1.77	0.045	0.070
с	0.35	0.64	0.014	0.025
c2	1.14	1.40	0.045	0.055
D	14.60	16.00	0.575	0.630
D1	2.62	3.44	0.103	0.135
D2	5.84	6.86	0.230	0.270
E	-	10.50	-	0.413
е	2.41	2.67	0.095	0.105
L	13.19	14.79	0.519	0.582
L4	2.80	4.20	0.110	0.165
Р	3.54	4.00	0.139	0.157

MARKING DIAGRAM



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf assumes no responsibility or liability for any errors or inaccuracies.

Purchasers are solely responsible for the choice, selection, and use of TSC products and TSC assumes no liability for application assistance or the design of Purchasers' products.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.